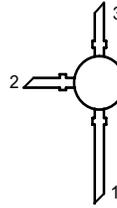




Silicon PNP Planar RF Transistor

Features

- High cross modulation performance
- High power gain
- Low noise
- High reverse attenuation
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Electrostatic sensitive device.
Observe precautions for handling.

13623

Applications

UHF/VHF uncontrolled prestages with low noise and low modulation.

Mechanical Data

Case: TO-50 Plastic case

Weight: approx. 111 mg

Marking: BF970

Pinning: 1 = Collector, 2 = Base, 3 = Emitter

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Collector-base voltage		$-V_{CBO}$	20	V
Collector-emitter voltage		$-V_{CEO}$	20	V
Emitter-base voltage		$-V_{EBO}$	3	V
Collector current		$-I_C$	50	mA
Total power dissipation	$T_{amb} \leq 60\text{ }^{\circ}\text{C}$	P_{tot}	300	mW
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$

Maximum Thermal Resistance

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	1)	R_{thJA}	300	K/W

1) on glass fibre printed board (40 x 25 x 1.5) mm³ plated with 35 μm Cu

Electrical DC Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector cut-off current	$-V_{CE} = 20\text{ V}, V_{BE} = 0$	$-I_{CES}$			100	μA
Collector-base cut-off current	$-V_{CB} = 15\text{ V}, I_E = 0$	$-I_{CBO}$			100	nA
Emitter-base cut-off current	$-V_{EB} = 3\text{ V}, I_C = 0$	$-I_{EBO}$			10	μA
Collector-emitter breakdown voltage	$-I_C = 1\text{ mA}, I_B = 0$	$-V_{(BR)CEO}$	20			V
DC forward current transfer ratio	$-V_{CE} = 10\text{ V}, -I_C = 10\text{ mA}$	h_{FE}	20	50	90	

Electrical AC Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Transition frequency	$-V_{CE} = 10\text{ V}$, $-I_C = 10\text{ mA}$, $f = 300\text{ MHz}$	f_T		1750		MHz
	$-V_{CE} = 10\text{ V}$, $-I_C = 30\text{ mA}$, $f = 300\text{ MHz}$	f_T		1300		MHz
Collector-base capacitance	$-V_{CB} = 10\text{ V}$, $f = 100\text{ MHz}$	C_{cb}		0.6		pF
Noise figure	$-V_{CE} = 10\text{ V}$, $-I_C = 10\text{ mA}$, $Z_S = 50\ \Omega$, $f = 800\text{ MHz}$	F		3.4	4.2	dB
Power gain	$-V_{CE} = 10\text{ V}$, $-I_C = 10\text{ mA}$, $Z_S = 50\ \Omega$, $Z_L = 500\ \Omega$, $f = 800\text{ MHz}$	G_{pb}		16		dB
Collector current for G_{pbmax}	$-V_{CE} = 10\text{ V}$, $Z_L = 500\ \Omega$, $f = 800\text{ MHz}$	$-I_C$		10		mA

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

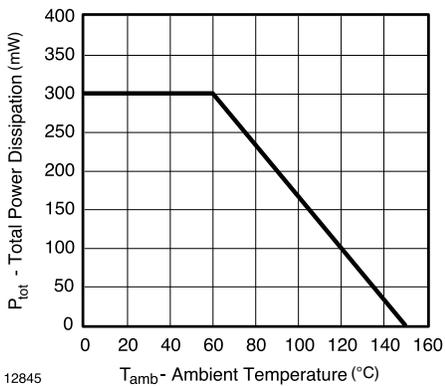


Figure 1. Total Power Dissipation vs. Ambient Temperature

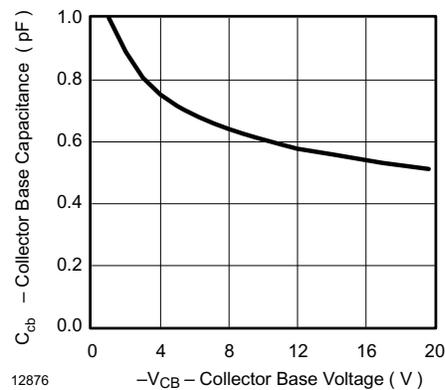


Figure 3. Collector Base Capacitance vs. Collector Base Voltage

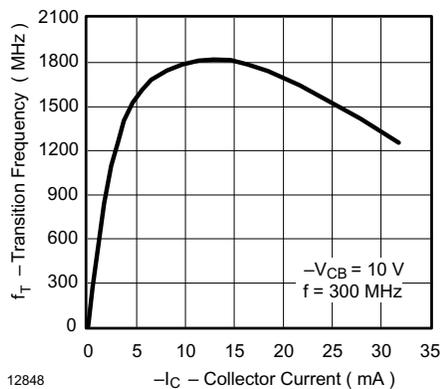
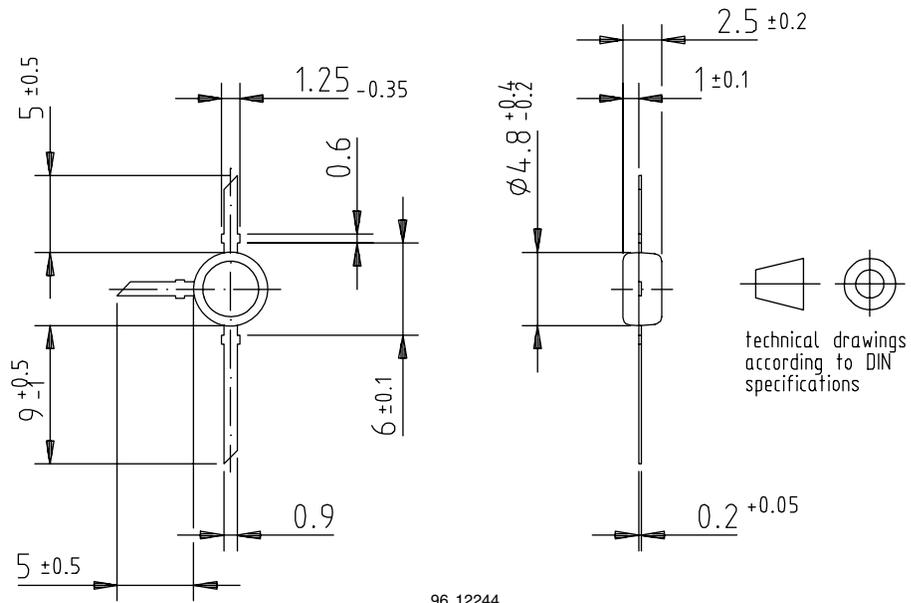


Figure 2. Transition Frequency vs. Collector Current

Package Dimensions in mm



96 12244

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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